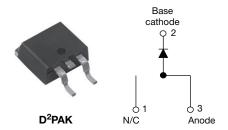


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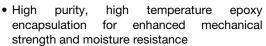
## Schottky Rectifier, 16 A



PRODUCT SUMMARY					
I <sub>F(AV)</sub>	16 A				
V <sub>R</sub>	35 V/45 V				
I <sub>RM</sub>	40 mA at 125 °C				

#### **FEATURES**

- 150 °C T<sub>J</sub> operation
- High frequency operation
- · Low forward voltage drop





- Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Halogen-free according to IEC 61249-2-21 definition
- Compliant to RoHS directive 2002/95/EC
- AEC-Q101 qualified

#### **DESCRIPTION**

This VS-MBRB16... Schottky rectifier has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS						
SYMBOL	CHARACTERISTICS	VALUES	UNITS			
I <sub>F(AV)</sub>	Rectangular waveform	16	А			
V <sub>RRM</sub>		35/45	V			
I <sub>FSM</sub>	t <sub>p</sub> = 5 μs sine	1800	A			
V <sub>F</sub>	16 Apk, T <sub>J</sub> = 125 °C	0.57	V			
T <sub>J</sub>		- 65 to 150	°C			

VOLTAGE RATINGS						
PARAMETER	SYMBOL	VS-MBRB1635PbF	VS-MBRB1645PbF	UNITS		
Maximum DC reverse voltage	$V_{R}$	35	45	V		
Maximum working peak reverse voltage	$V_{RWM}$	33	45	V		

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST CONI	VALUES	UNITS			
Maximum average forward current	I <sub>F(AV)</sub>	T <sub>C</sub> = 134 °C, rated V <sub>R</sub>	T <sub>C</sub> = 134 °C, rated V <sub>R</sub>				
Non-repetitive peak surge current	I <sub>FSM</sub>	5 μs sine or 3 μs rect. pulse	Following any rated load condition and with rated V <sub>RRM</sub> applied	1800	Α		
		Surge applied at rated load condition halfwave single phase 60 Hz		150			
Non-repetitive avalanche energy	E <sub>AS</sub>	$T_J = 25  ^{\circ}\text{C},  I_{AS} = 3.6  \text{A},  L = 3.7  \text{mH}$		24	mJ		
Repetitive avalanche current	I <sub>AR</sub>	Current decaying linearly to zero in 1 $\mu$ s Frequency limited by T <sub>J</sub> maximum V <sub>A</sub> = 1.5 x V <sub>R</sub> typical		3.6	А		

Document Number: 94304 Revision: 23-Jun-10

# VS-MBRB1635PbF, VS-MBRB1645PbF

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ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CO	VALUES	UNITS		
Maximum forward voltage drop	V (1)	V <sub>FM</sub> <sup>(1)</sup> 16 A	T <sub>J</sub> = 25 °C	0.63	V	
Maximum forward voltage drop	V <sub>FM</sub> ('')		T <sub>J</sub> = 125 °C	0.57		
Maximum instantaneous	I <sub>RM</sub> <sup>(1)</sup>	T <sub>J</sub> = 25 °C	Rated DC voltage	0.2	mA	
reverse current	IRM (*)	T <sub>J</sub> = 125 °C	hated DC voltage	40		
Maximum junction capacitance	C <sub>T</sub>	V <sub>R</sub> = 5 V <sub>DC</sub> (test signal range	1400	pF		
Typical series inductance	L <sub>S</sub>	Measured lead from top or	8.0	nΗ		
Maximum voltage rate of change	dV/dt	Rated V <sub>R</sub>	10 000	V/µs		

#### Note

 $<sup>^{(1)}\,</sup>$  Pulse width < 300  $\mu s,$  duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum junction temperature	range	$T_J$		- 65 to 150	°C		
Maximum storage temperature	range	$T_{Stg}$		- 65 to 175	C		
Maximum thermal resistance, junction to case		R <sub>thJC</sub>	DC operation		°C/W		
Typical thermal resistance, case to heatsink		R <sub>thCS</sub>	Mounting surface, smooth and greased	0.50	C/VV		
Approximate weight				2	g		
				0.07	OZ.		
Mounting torque -	minimum			6 (5)	kgf · cm		
wounting torque =	maximum			12 (10)	(lbf $\cdot$ in)		
Marking device Case style D <sup>2</sup> PAK		MBRE	31645				



### Schottky Rectifier, 16 A

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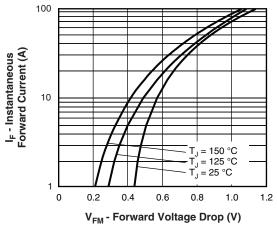


Fig. 1 - Maximum Forward Voltage Drop Characteristics

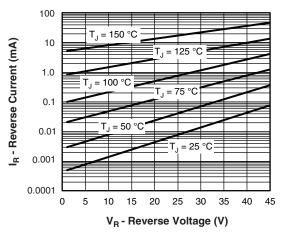


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

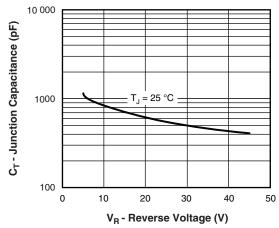


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

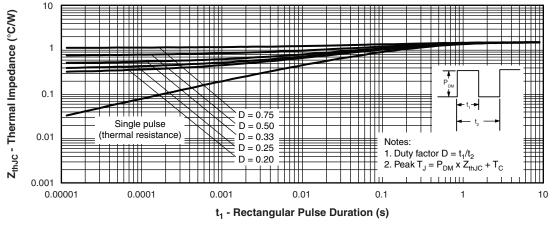


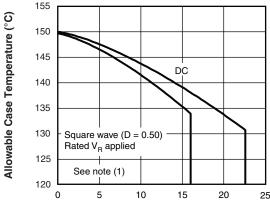
Fig. 4 - Maximum Thermal Impedance Z<sub>thJC</sub> Characteristics

# VS-MBRB1635PbF, VS-MBRB1645PbF

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### Schottky Rectifier, 16 A





I<sub>F(AV)</sub> - Average Forward Current (A)

Fig. 5 - Maximum Allowable Case Temperature vs.
Average Forward Current

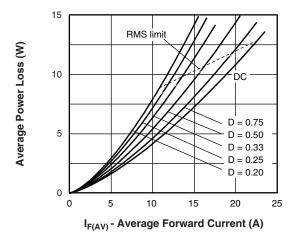
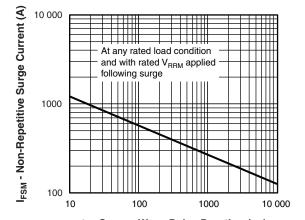


Fig. 6 - Forward Power Loss Characteristics



 $t_p$  - Square Wave Pulse Duration ( $\mu$ s) Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

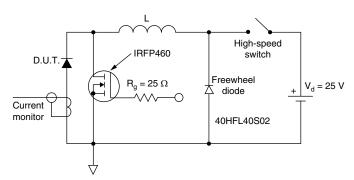


Fig. 8 - Unclamped Inductive Test Circuit

#### Note

 $\begin{array}{ll} \text{(1)} & \text{Formula used: } T_C = T_J - (Pd + Pd_{REV}) \times R_{th,JC}; \\ Pd = \text{Forward power loss} = I_{F(AV)} \times V_{FM} \text{ at } (I_{F(AV)}/D) \text{ (see fig. 6);} \\ Pd_{REV} = \text{Inverse power loss} = V_{R1} \times I_R \text{ (1 - D); } I_R \text{ at } V_{R1} = \text{Rated } V_R \text{ applied} \\ \end{array}$ 



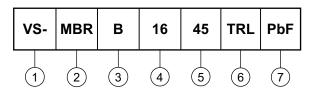
# VS-MBRB1635PbF, VS-MBRB1645PbF

Schottky Rectifier, 16 A

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#### **ORDERING INFORMATION TABLE**

Device code



1 - HPP product suffix

2 - Essential part number

- B = Surface mount

Current rating (16 = 16 A)

- Voltage code = V<sub>RRM</sub> 35 = 35 V 45 = 45 V

6 - • None = Tube (50 pieces)

• TRL = Tape and reel (left oriented)

• TRR = Tape and reel (right oriented)

7 - PbF = Lead (Pb)-free

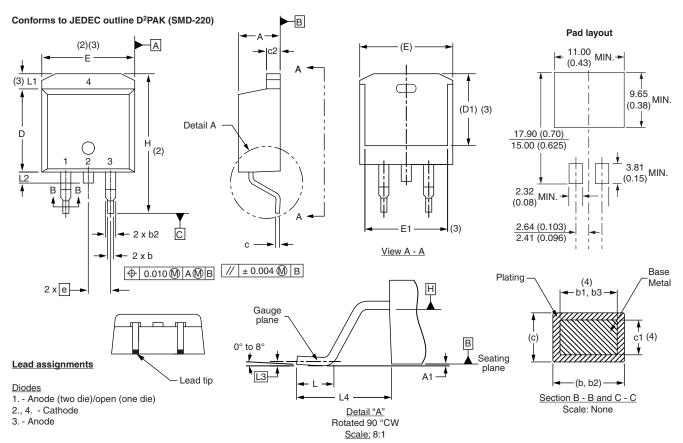
LINKS TO RELATED DOCUMENTS					
Dimensions	www.vishay.com/doc?95046				
Part marking information	www.vishay.com/doc?95054				
Packaging information	www.vishay.com/doc?95032				
SPICE model	www.vishay.com/doc?95407				



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### D<sup>2</sup>PAK

#### **DIMENSIONS** in millimeters and inches



SYMBOL	MILLIMETERS		INC	NOTES	
STWIDOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.06	4.83	0.160	0.190	
A1	0.00	0.254	0.000	0.010	
b	0.51	0.99	0.020	0.039	
b1	0.51	0.89	0.020	0.035	4
b2	1.14	1.78	0.045	0.070	
b3	1.14	1.73	0.045	0.068	4
С	0.38	0.74	0.015	0.029	
c1	0.38	0.58	0.015	0.023	4
c2	1.14	1.65	0.045	0.065	
D	8.51	9.65	0.335	0.380	2

SYMBOL	MILLIM	ETERS	INC	NOTES	
STWBOL	MIN.	MAX.	MIN.	MAX.	NOTES
D1	6.86	8.00	0.270	0.315	3
E	9.65	10.67	0.380	0.420	2, 3
E1	7.90	8.80	0.311	0.346	3
е	2.54 BSC		0.100 BSC		
Н	14.61	15.88	0.575	0.625	
L	1.78	2.79	0.070	0.110	
L1	-	1.65	1	0.066	3
L2	1.27	1.78	0.050	0.070	
L3	0.25 BSC		0.010	BSC	
L4	4.78	5.28	0.188	0.208	

#### Notes

- $^{(1)}$  Dimensioning and tolerancing per ASME Y14.5 M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- (3) Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Datum A and B to be determined at datum plane H
- (6) Controlling dimension: inch
- (7) Outline conforms to JEDEC outline TO-263AB





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